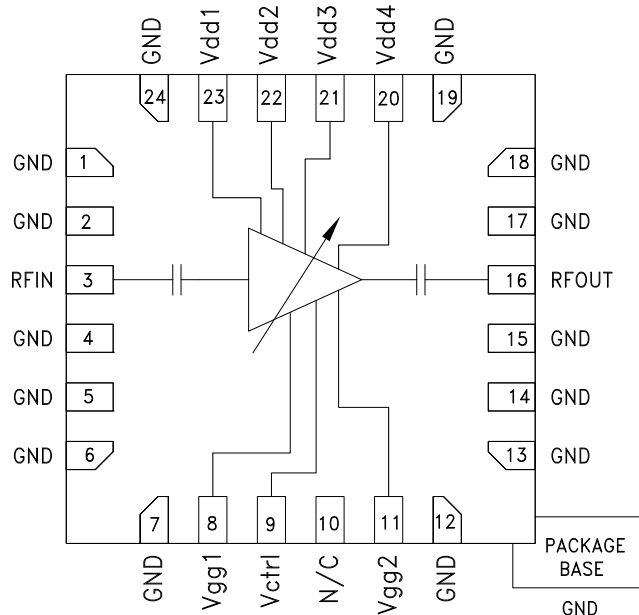


Typical Applications

The HMC6187LP4E is ideal for:

- Point-to-Point Radio
- Point-to-Multi-Point Radio
- EW & ECM Subsystems
- Ka-Band Radar & VSAT
- Test Equipment

Functional Diagram



Features

- Wide Gain Control Range: 13 dB
- Single Control Voltage
- Output IP3 @ Max Gain: +31 dBm
- Output P1dB: +24 dBm
- No External Matching
- 24 Lead 4x4 mm SMT Package: 16 mm²

General Description

The HMC6187LP4E is a GaAs MMIC pHEMT analog variable gain amplifier and/or driver amplifier which operates between 27 and 31.5 GHz and is ideal for microwave radio applications. The amplifier provides up to 19 dB of gain, output P1dB of up to +24 dBm, and up to +31 dBm of output IP3 at maximum gain, while requiring 230 mA from a +5V supply. A gain control voltage (Vctrl) is provided to allow variable gain control up to 13 dB. Gain flatness is excellent making the HMC6187LP4E ideal for EW, ECM and radar applications. The HMC6187LP4E is housed in a RoHS compliant 4 x 4 mm plastic QFN leadless package and is compatible with high volume surface mount manufacturing.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{dd1, 2, 3, 4} = 5\text{V}$, $V_{ctrl} = -4.5\text{V}$, $I_{dd} = 230\text{ mA}$ ^[1]

Parameter	Min.	Typ.	Max.	Units
Frequency Range		27 - 31.5		GHz
Gain ^[2]	16	19		dB
Gain Flatness		±0.5		dB
Gain Variation Over Temperature		0.02		dB/ °C
Gain Control Range		13		dB
Noise Figure ^[2]		4.5		dB
Input Return Loss		12		dB
Output Return Loss		15		dB
Output Power for 1 dB Compression (P1dB) ^[2]	21	24		dBm
Saturated Output Power (Psat) ^[2]		25		dBm
Output Third Order Intercept (IP3) ^[2]		31		dBm
Total Supply Current (Idd)		230		mA

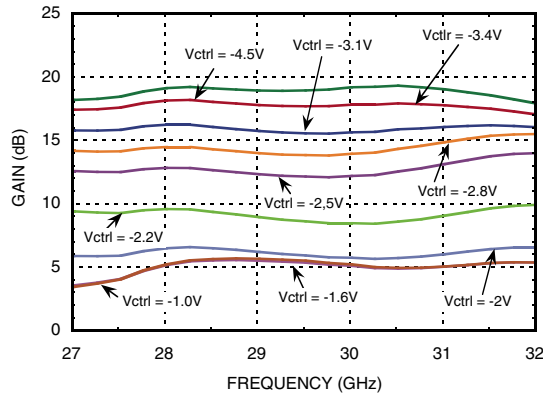
^[1] Set Vctrl = -4.5V and then adjust Vgg1, 2 between -2V to 0V to achieve Idd = 230 mA typical.

^[2] Board loss subtracted out.

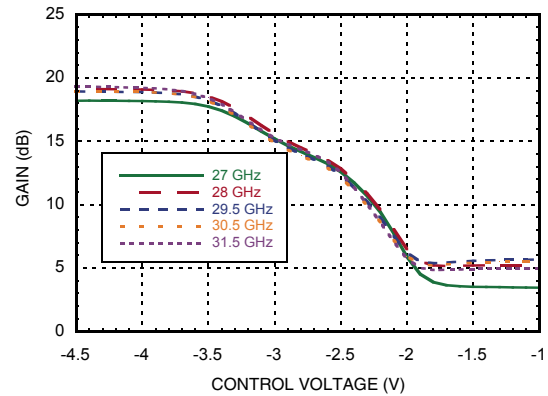


**VARIABLE GAIN AMPLIFIER
27 - 31.5 GHz**

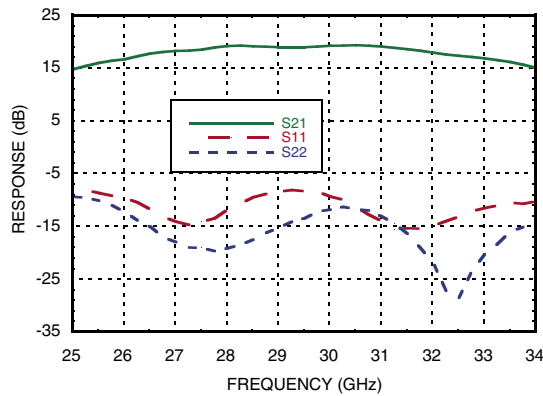
Gain vs. Control Voltage Range



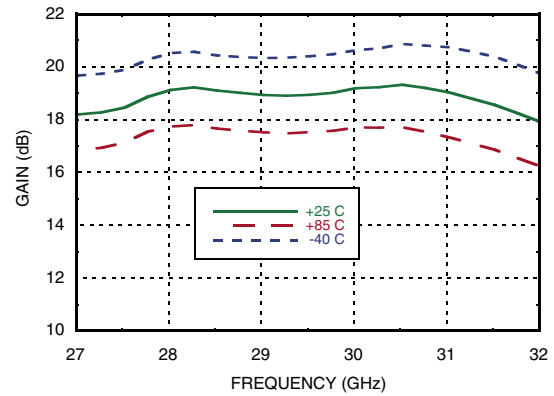
Gain vs. Control Voltage



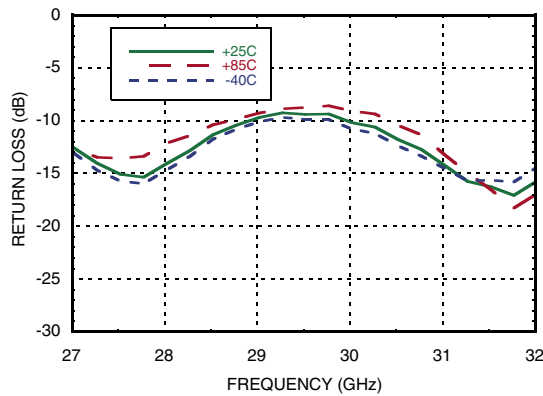
Broadband Gain & Return Loss



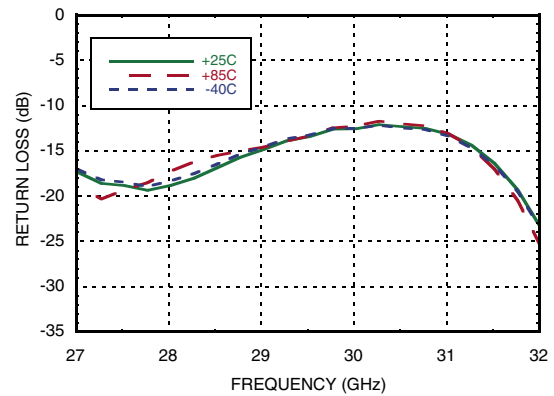
Gain vs. Temperature



Input Return Loss vs. Temperature



Output Return Loss vs. Temperature

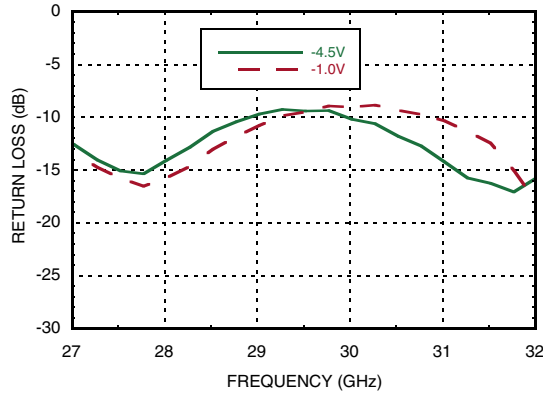




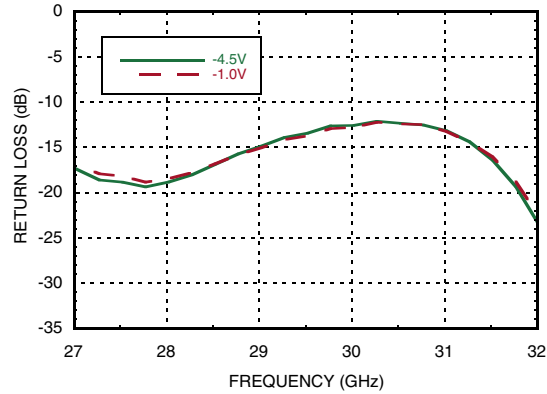
VARIABLE GAIN AMPLIFIER 27 - 31.5 GHz

VARIABLE GAIN AMPLIFIER - SMT

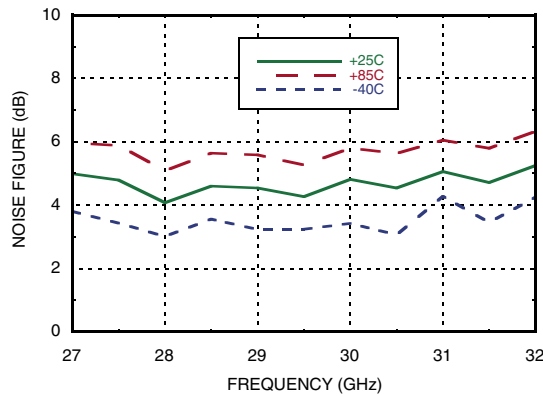
**Input Return Loss @
Control Voltage Extreme**



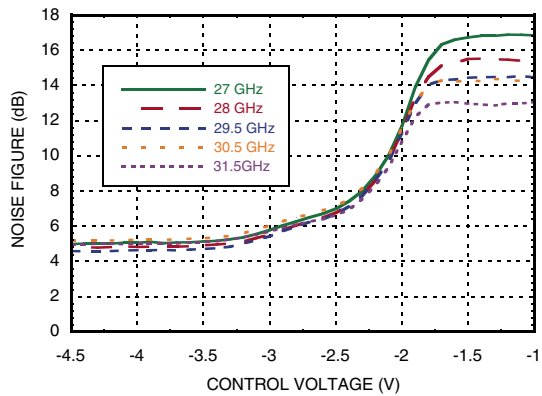
**Output Return Loss @
Control Voltage Extreme**



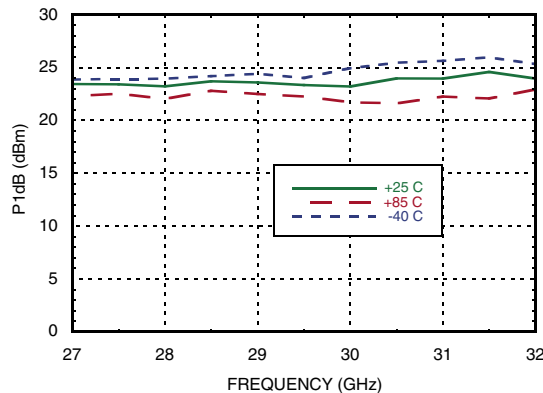
Noise Figure vs. Temperature



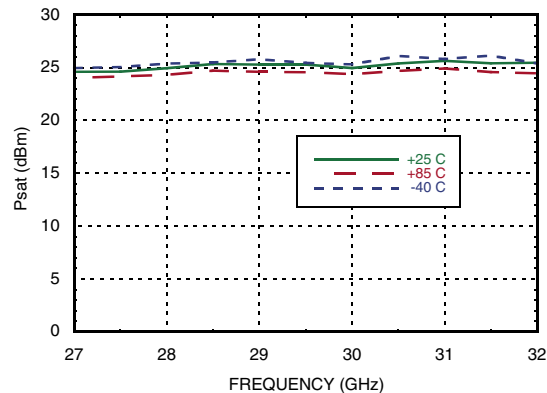
Noise Figure vs. Control Voltage



P1dB vs. Temperature, Vctrl = -4.5V



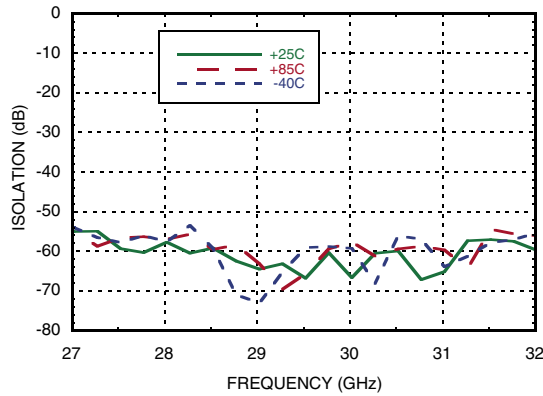
Psat vs. Temperature, Vctrl = -4.5V



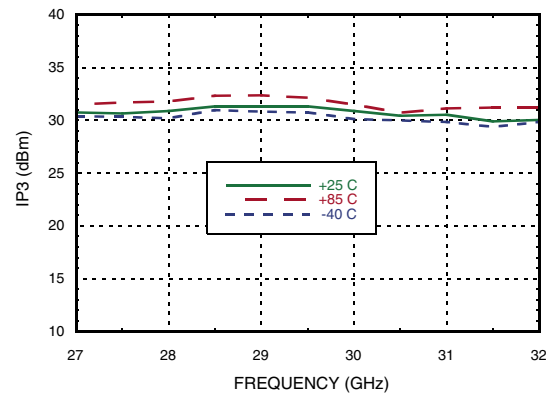


VARIABLE GAIN AMPLIFIER 27 - 31.5 GHz

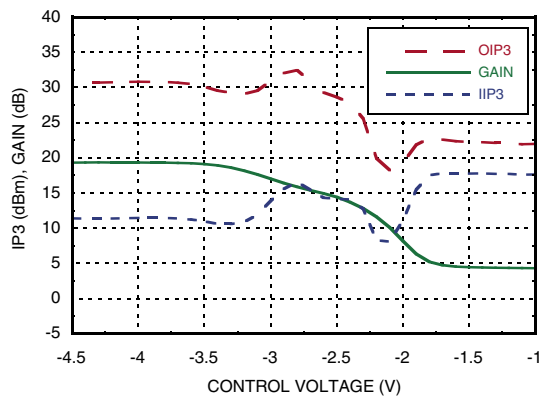
Reverse Isolation vs. Temperature



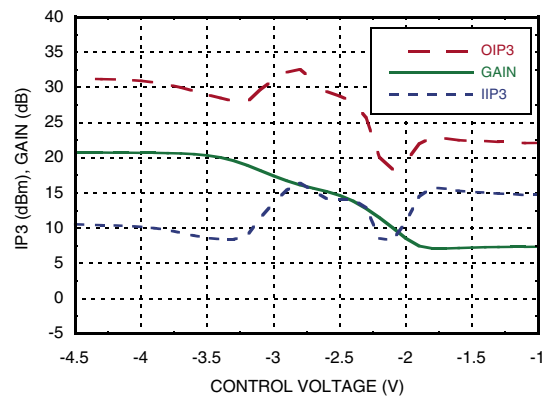
Output IP3 vs. Temperature, Vctrl=-4.5V



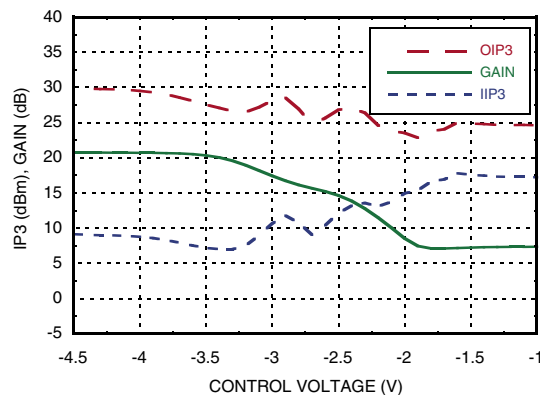
IP3 and Gain @ 27 GHz Pin = -7 dBm



IP3 and Gain @ 29.5 GHz Pin = -7 dBm



IP3 and Gain @ 31.5 GHz Pin = -7 dBm





Absolute Maximum Ratings

Drain Bias Voltage (Vdd1, 2, 3)	+5.5V
Gate Bias Voltage (Vgg1, 2)	-2.5 to 0V
Gain Control Voltage (Vctrl)	-5 to 0V
RF Power Input (RFIN)	+5 dBm
Channel Temperature	175 °C
Continuous P _{diss} (T = 85 °C) (derate 20.3 mW/°C above 85 °C) [1]	1.83 W
Thermal Resistance (Channel to ground paddle)	49.2 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 0 Passed 100V

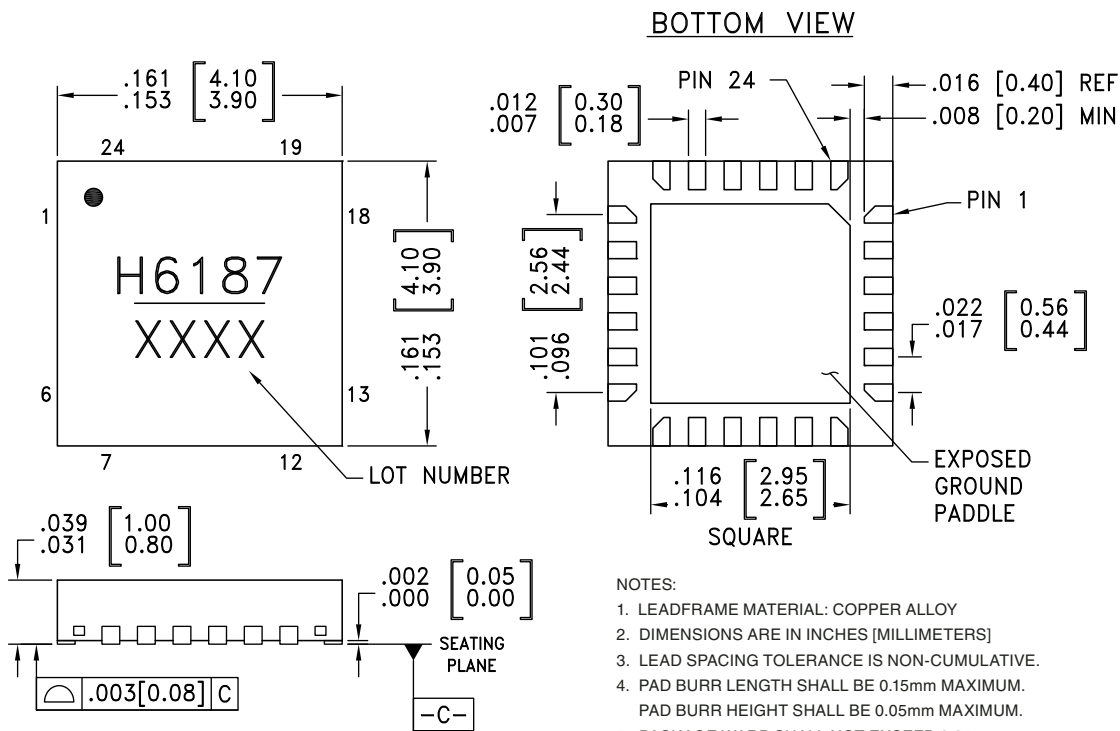
Bias Voltage

Vdd1,2,3 (V)	I _{dd} Total (mA)
+5V	230
Vgg1,2 (V)	I _{gg} Total (mA)
0V to -2V	<0.2 mA
Vctrl (V)	I _{ctrl} (mA)
-4.5V to -1V	<1 mA



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



NOTES:

- LEADFRAME MATERIAL: COPPER ALLOY
- DIMENSIONS ARE IN INCHES [MILLIMETERS]
- LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.


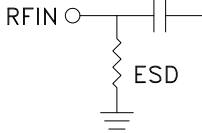
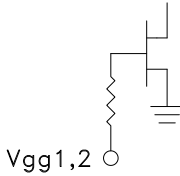
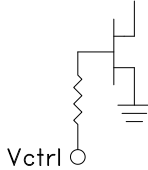
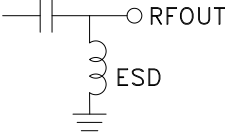
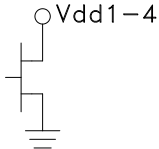
Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC6187LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [1]	H6187 XXXX

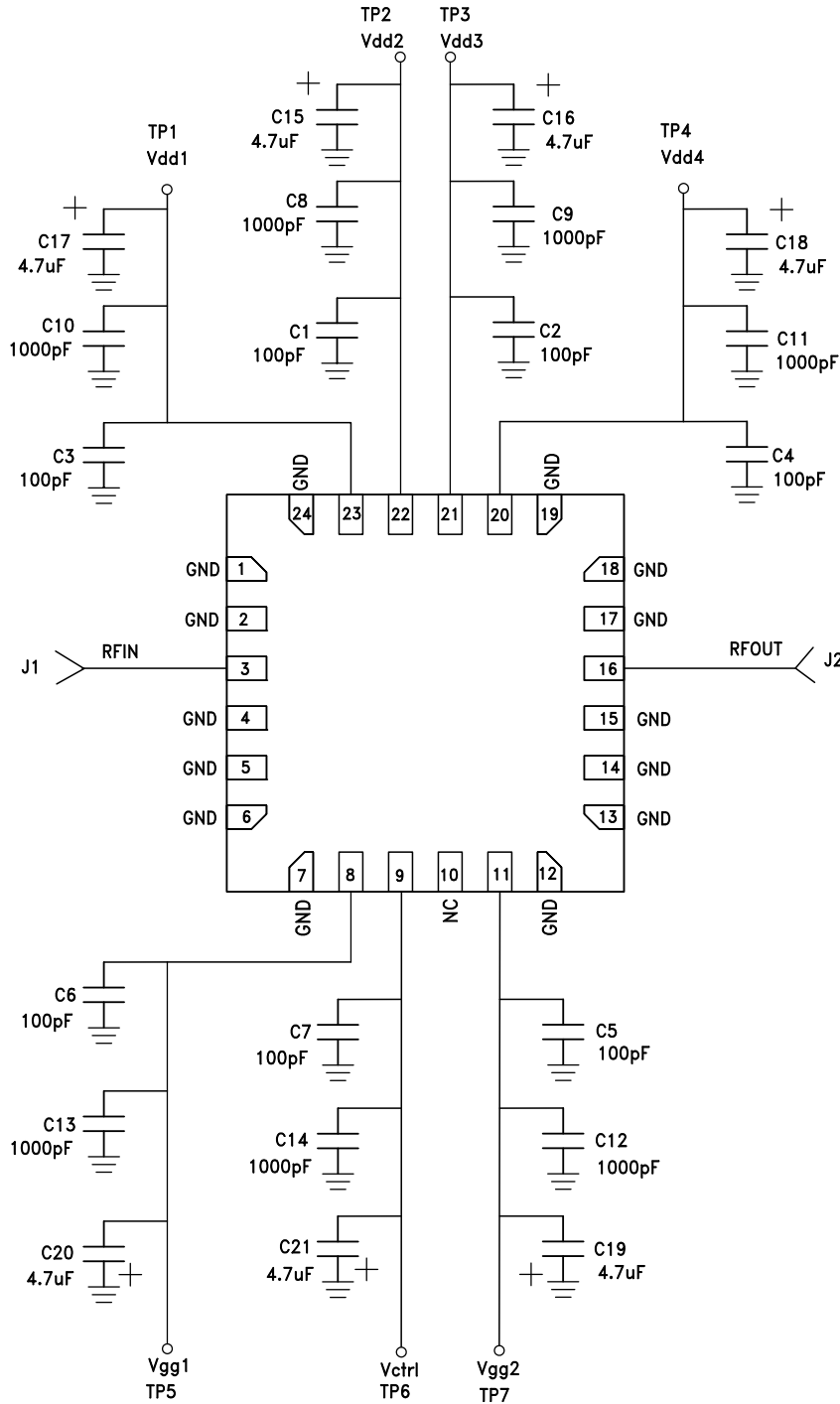
[1] Max peak reflow temperature of 260 °C

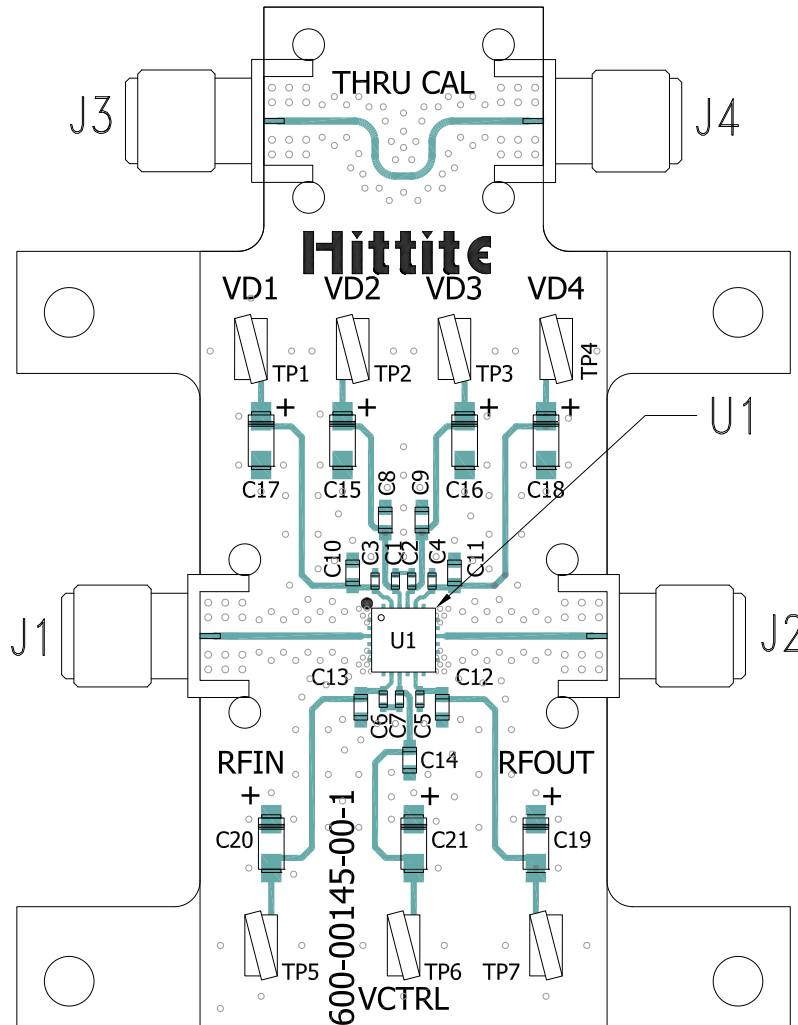
[2] 4-Digit lot number XXXX

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 2, 4, 5, 6, 7, 12, 13, 14, 15, 17, 18, 19, 24	GND	These pins and exposed ground paddle must be connected to RF/DC ground.	
3	RFIN	This pin is AC coupled and matched to 50 Ohms.	
8, 11	Vgg1, 2	Adjust voltage to achieve typical I _{dd} . Please follow "MMIC Amplifier Biasing Procedure" application note.	
9	Vctrl	Gain control Voltage for the amplifier. See assembly diagram for required external components.	
10	NC	The pins are not connected internally; however all data shown herein was measured with these pins connected to RF/DC ground externally.	
16	RFOUT	This pad is AC coupled and matched to 50 Ohms.	
20, 21, 22, 23	Vdd4, 3, 2, 1	Drain Bias Voltage for the amplifier. See assembly diagram for required external components	

Application Circuit



Evaluation PCB

**List of Materials for Evaluation PCB
EVAL01-HMC6187LP4E [1]**

Item	Description
J1 - J4	PCB Mount K Connectors
TP1 - TP7	DC Pin
C1 - C7	100 pF Capacitor, 0402 Pkg.
C8 - C14	10,000 pF Capacitor, 0603 Pkg.
C15 - C21	4.7 μ F Capacitor, CASE A
U1	HMC6187LP4E Variable Gain Amplifier
PCB [2]	600-00145-00 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.